FAST RECOVERY RECTIFIER

VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 2.0 A

FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability

MECHANICAL DATA

- ◇ Case:JEDEC DO-41,molded plastic
- ◇ Terminals: Axial lead ,solderable per MIL- STD-202,Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.012 ounces,0.34 grams
- ◇ Mounting position: Any

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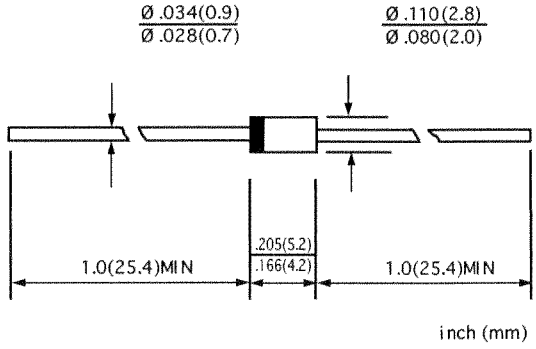

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.
Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		MR 810	MR 811	MR 812	MR 814	MR 816	MR 817	MR 818	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 9.5mm lead length, @T_A=75℃	$I_{F(AV)}$	2.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @T_J=125℃	I_{FSM}	30.0							A
Maximum instantaneous forward voltage @ 2.0 A	V_F	1.2							V
Maximum reverse current @T_A=25℃ at rated DC blocking voltage @T_A=100℃	I_R	5.0 100.0							μA
Maximum reverse recovery time (Note1)	t_{rr}	750							ns
Typical junction capacitance (Note2)	C_J	18							pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	45							℃/W
Operating junction temperature range	T_J	- 55---- +150							℃
Storage temperature range	T_{STG}	- 55---- +150							℃

NOTE:1. Measured with I_F=0.5A, I_R=1A, I_{rr}=0.25A.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.